MAXIM

2.375V to 5.25V, 4-Wire Touch-Screen Controller with Internal Reference and Temperature Sensor

MXB7846

General Description

The MXB7846 is an industry-standard 4-wire touch-screen controller. It contains a 12-bit sampling analog-to-digital converter (ADC) with a synchronous serial interface and low on-resistance switches for driving resistive touch screens. The MXB7846 uses an internal +2.5V reference or an external reference. The MXB7846 can make absolute or ratiometric measurements. In addition, this device has an on-chip temperature sensor, a battery-monitoring channel, and has the ability to perform touch-pressure measurements without external components. The MXB7846 has one auxiliary ADC input. All analog inputs are fully ESD protected, eliminating the need for external TransZorb™ devices.

The MXB7846 is guaranteed to operate with a supply voltage down to +2.375V when used with an external reference or +2.7V with an internal reference. In shutdown mode, the typical power consumption is reduced to under 0.5µW, while the typical power consumption at 125ksps throughput and a +2.7V supply is 650µW.

Low-power operation makes the MXB7846 ideal for battery-operated systems, such as personal digital assistants with resistive touch screens and other portable equipment. The MXB7846 is available in 16-pin QSOP and TSSOP packages, and is guaranteed over the -40°C to +85°C temperature range.

Applications

Personal Digital Assistants

Portable Instruments

Point-of-Sales Terminals

Pagers

Touch-Screen Monitors

Cellular Phones

Typical Application Circuit appears at end of data sheet.

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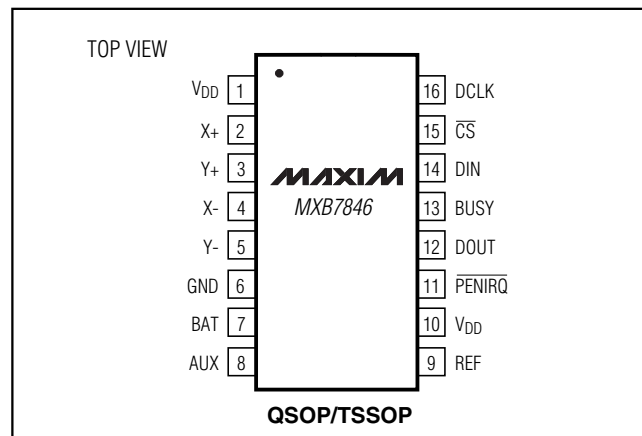
SPI/QSPI are trademarks of Motorola, Inc.

Features

♦ **ESD-Protected ADC Inputs**
  ±15kV IEC 61000-4-2 Air-Gap Discharge
  ±8kV IEC 61000-4-2 Contact Discharge

♦ **Pin Compatible with MXB7843**

♦ **+2.375V to +5.25V Single Supply**

♦ **Internal +2.5V Reference**

♦ **Direct Battery Measurement (0 to 6V)**

♦ **On-Chip Temperature Measurement**

♦ **Touch-Pressure Measurement**

♦ **4-Wire Touch-Screen Interface**

♦ **Ratiometric Conversion**

♦ **SPI™/QSPI™, 3-Wire Serial Interface**

♦ **Programmable 8-/12-Bit Resolution**

♦ **Auxiliary Analog Input**

♦ **Automatic Shutdown Between Conversions**

♦ **Low Power (External Reference)**
  270µA at 125ksps
  115µA at 50ksps
  25µA at 10ksps
  5µA at 1ksps
  2µA Shutdown Current

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MXB7846EEE	-40°C to +85°C	16 QSOP
MXB7846EUE	-40°C to +85°C	16 TSSOP

Pin Configuration

TOP VIEW

```
         VDD  1          16  DCLK
         X+   2          15  CS
         Y+   3          14  DIN
              MAXIM
         X-   4  MXB7846 13  BUSY
         Y-   5          12  DOUT
         GND  6          11  PENIRQ
         BAT  7          10  VDD
         AUX  8           9  REF
```

QSOP/TSSOP

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For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

2.375V to 5.25V, 4-Wire Touch-Screen Controller with Internal Reference and Temperature Sensor

ABSOLUTE MAXIMUM RATINGS

V$_{DD}$, VBAT, DIN, $\overline{CS}$, DCLK to GND ....-0.3V to +6V
Digital Outputs to GND...............................-0.3V to (V$_{DD}$ + 0.3V)
V$_{REF}$, X+, X-, Y+, Y-, AUX to GND..............-0.3V to (V$_{DD}$ + 0.3V)
Maximum Current into Any Pin ....±50mA
Maximum ESD per IEC-61000-4-2 (per MIL STD-883 HBM)
    X+, X-, Y+, Y-, VBAT, AUX 15kV (4kV)
    All Other Pins 2kV (500V)

Continuous Power Dissipation (T$_A$ = +70°C)
    16-Pin QSOP (derate 8.30mW/°C above +70°C).........667mW
    16-Pin TSSOP (derate 5.70mW/°C above +70°C) 456mW
Operating Temperature Range ....-40°C to +85°C
Junction Temperature..+150°C
Storage Temperature Range ....-65°C to +150°C
Lead Temperature (soldering, 10s) ....+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V$_{DD}$ = 2.7V to 3.6V, V$_{REF}$ = 2.5V, f$_{DCLK}$ = 2MHz (50% duty cycle), f$_{SAMPLE}$ = 125kHz, 12-bit mode, 0.1µF capacitor at REF, T$_A$ = T$_{MIN}$ to T$_{MAX}$, unless otherwise noted. Typical values are at T$_A$ = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
DC ACCURACY (Note 1)						
Resolution					12	Bits
No Missing Codes			11	12		Bits
Relative Accuracy	INL	(Note 2)		±1	±2	LSB
Differential Nonlinearity	DNL			±1		LSB
Offset Error					±6	LSB
Gain Error		(Note 3)			±4	LSB
Noise		Including internal reference		70		µV$_{RMS}$
CONVERSION RATE						
Conversion Time	t$_{CONV}$	12 clock cycles (Note 4)			6	µs
Track/Hold Acquisition Time	t$_{ACQ}$	3 clock cycles	1.5			µs
Throughput Rate	f$_{SAMPLE}$	16 clock conversion			125	kHz
Multiplexer Settling Time				500		ns
Aperture Delay				30		ns
Aperture Jitter				100		ps
Channel-to-Channel Isolation		V$_{IN}$ = 2.5V$_{P-P}$ at 50kHz		100		dB
Serial Clock Frequency	f$_{DCLK}$		0.1		2.0	MHz
Duty Cycle			40		60	%
ANALOG INPUT (X+, X-, Y+, Y-, AUX)						
Input Voltage Range			0		V$_{REF}$	V
Input Capacitance				25		pF
Input Leakage Current		On/off leakage, V$_{IN}$ = 0 to V$_{DD}$		±0.1	±1	µA
SWITCH DRIVERS						
On-Resistance (Note 5)		Y+, X+		7		Ω
		Y-, X-		9		
INTERNAL REFERENCE						
Reference Output Voltage	V$_{REF}$	V$_{DD}$ = 2.7V to 5.25V, T$_A$ = +25°C	2.45	2.50	2.55	V
REF Output Tempco	TCV$_{REF}$			50		ppm°/C
REF Short-Circuit Current				18		mA
REF Output Impedance				250		Ω

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2.375V to 5.25V, 4-Wire Touch-Screen Controller with Internal Reference and Temperature Sensor

ELECTRICAL CHARACTERISTICS (continued)

(V_{DD} = 2.7V to 3.6V, V_{REF} = 2.5V, f_{DCLK} = 2MHz (50% duty cycle), f_{SAMPLE} = 125kHz, 12-bit mode, 0.1µF capacitor at REF, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
EXTERNAL REFERENCE (Internal reference disabled, reference applied to REF)						
Reference Input Voltage Range		(Note 7)	1		V_{DD}	V
Input Resistance				1		GΩ
Input Current		f_{SAMPLE} = 125kHz		13	40	µA
		f_{SAMPLE} = 12.5kHz		2.5		
		f_{DCLK} = 0			±3	
BATTERY MONITOR (BAT)						
Input Voltage Range			0		6	V
Input Resistance		During acquisition		10		kΩ
Accuracy		V_{REF} = 2.5V			±2	%
		Internal reference			±3	
TEMPERATURE MEASUREMENT						
Resolution		Differential method (Note 8)		1.6		°C
		Single-conversion method		0.3		°C
Accuracy		Differential method (Note 8)		±2		°C
		Single-conversion method		±3		°C
DIGITAL INPUTS (DCLK, $\overline{CS}$, DIN)						
Input High Voltage	V_{IH}		$V_{DD} \times 0.7$			V
Input Low Voltage	V_{IL}				0.8	V
Input Hysteresis	V_{HYST}			100		mV
Input Leakage Current	I_{IN}				±1	µA
Input Capacitance	C_{IN}			15		pF
DIGITAL OUTPUT (DOUT, BUSY)						
Output Voltage Low	V_{OL}	I_{SINK} = 250µA			0.4	V
Output Voltage High	V_{OH}	I_{SOURCE} = 250µA	V_{DD} - 0.5			V
$\overline{PENIRQ}$ Output Low Voltage	V_{OL}	50kΩ pullup to V_{DD}			0.8	V
Three-State Leakage Current	I_L	$\overline{CS}$ = V_{DD}		1	±10	µA
Three-State Output Capacitance	C_{OUT}	$\overline{CS}$ = V_{DD}		15		pF
POWER REQUIREMENTS						
Supply Voltage	V_{DD}	External reference	2.375		5.250	V
		Internal reference	2.70		5.25	
Supply Current	I_{DD}	External reference — f_{SAMPLE} = 125ksps		270	650	µA
		External reference — f_{SAMPLE} = 12.5ksps		220		
		External reference — f_{SAMPLE} = 0		150		
		Internal reference — f_{SAMPLE} = 125ksps		780	950	µA
		Internal reference — f_{SAMPLE} = 12.5ksps		720		
		Internal reference — f_{SAMPLE} = 0		650		
Shutdown Supply Current	I_{SHDN}	DCLK = $\overline{CS}$ = V_{DD}			3	µA
Power-Supply Rejection Ratio	P_{SRR}	V_{DD} = 2.7V to 3.6V full scale		70		dB

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TIMING CHARACTERISTICS (Figure 1)

(V_{DD} = 2.7V to 3.6V, V_{REF} = 2.5V, f_{DCLK} = 2MHz (50% duty cycle), f_{SAMPLE} = 125kHz, 12-bit mode, 0.1μF capacitor at REF, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
TIMING CHARACTERISTICS (Figure 1)						
Acquisition Time	t_{ACQ}		1.5			μs
DCLK Clock Period	t_{CP}		500			ns
DCLK Pulse Width High	t_{CH}		200			ns
DCLK Pulse Width Low	t_{CL}		200			ns
DIN-to-DCLK Setup Time	t_{DS}		100			ns
DIN-to-DCLK Hold Time	t_{DH}		0			ns
$\overline{CS}$ Fall-to-DCLK Rise Setup Time	t_{CSS}		100			ns
$\overline{CS}$ Rise-to-DCLK Rise Ignore	t_{CSH}		0			ns
DCLK Falling-to-DOUT Valid	t_{DO}	C_{LOAD} = 50pF			200	ns
$\overline{CS}$ Rise-to-DOUT Disable	t_{TR}	C_{LOAD} = 50pF			200	ns
$\overline{CS}$ Fall-to-DOUT Enable	t_{DV}	C_{LOAD} = 50pF			200	ns
DCLK Falling-to-BUSY Rising	t_{BD}				200	ns
$\overline{CS}$ Falling-to-BUSY Enable	t_{BDV}				200	ns
$\overline{CS}$ Rise-to-BUSY Disable	t_{BTR}				200	ns

Note 1: Tested at V_{DD} = 2.7V.
Note 2: Relative accuracy is the deviation of the analog value at any code from its theoretical value after the full-scale range has been calibrated.
Note 3: Offset nulled.
Note 4: Conversion time is defined as the number of clock cycles multiplied by the clock period; clock has 50% duty cycle.
Note 5: Resistance measured from the source to drain of the switch.
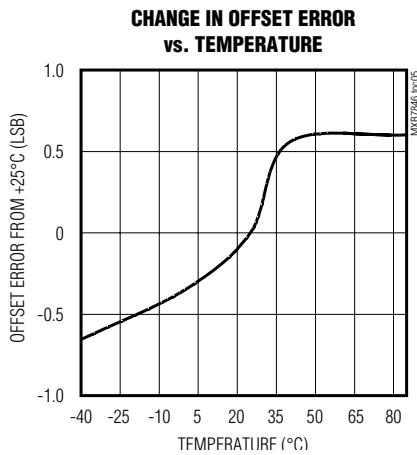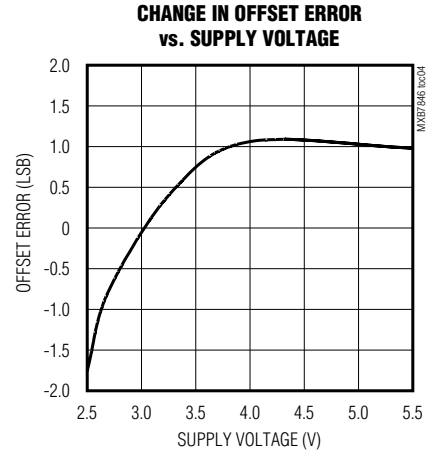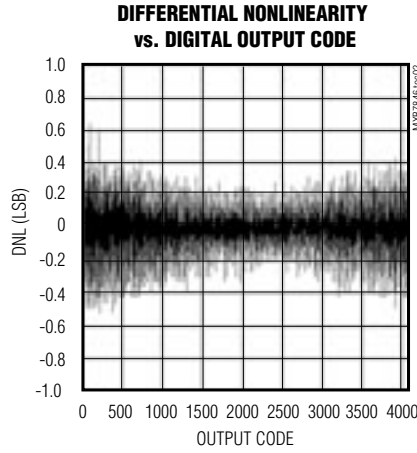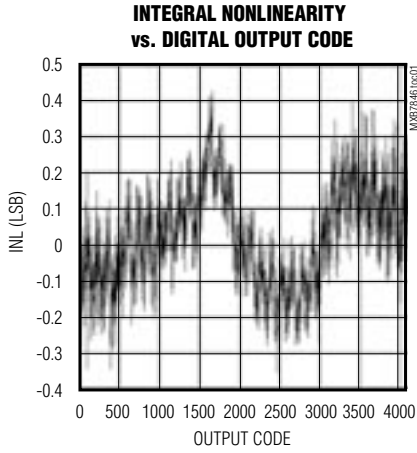**Note 6:** External load should not change during conversion for specified accuracy.
Note 7: ADC performance is limited by the conversion noise floor, typically 300μV$_{P-P}$. An external reference below 2.5V can compromise the ADC performance.
Note 8: Difference between Temp0 and Temp1. No calibration necessary.

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_____*Typical Operating Characteristics*

(V$_{DD}$ = 2.7V, V$_{REF}$ = 2.5V$_{EXTERNAL}$, f$_{DCLK}$ = 2MHz, f$_{SAMPLE}$ = 125kHz, C$_{LOAD}$ = 50pF, 0.1µF capacitor at REF, T$_A$ = +25°C, unless otherwise noted.)

INTEGRAL NONLINEARITY vs. DIGITAL OUTPUT CODE

DIFFERENTIAL NONLINEARITY vs. DIGITAL OUTPUT CODE

CHANGE IN OFFSET ERROR vs. SUPPLY VOLTAGE

CHANGE IN OFFSET ERROR vs. TEMPERATURE

CHANGE IN GAIN ERROR vs. SUPPLY VOLTAGE

CHANGE IN GAIN ERROR vs. TEMPERATURE

SWITCH ON-RESISTANCE vs. SUPPLY VOLTAGE
(X+, Y+ : +V$_{DD}$ TO PIN; X-, Y- : TO GND)

SWITCH ON-RESISTANCE vs. TEMPERATURE
(X+, Y+ : +V$_{DD}$ TO PIN; X-, Y- : PIN TO GND)

INTERNAL REFERENCE vs. SUPPLY VOLTAGE

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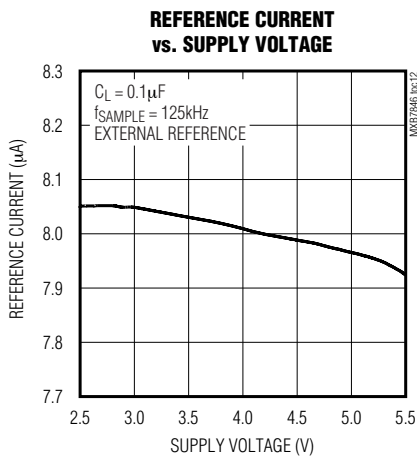MXB7846

_____Typical Operating Characteristics (continued)
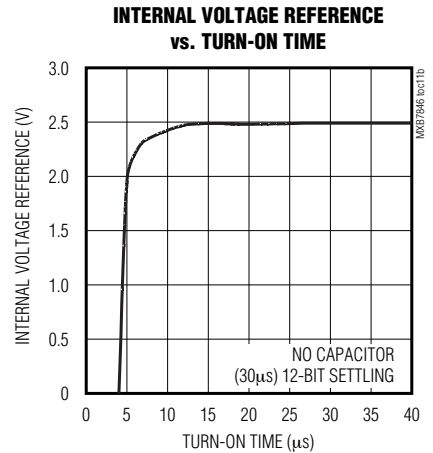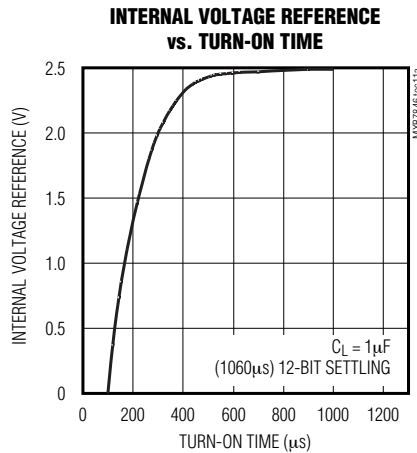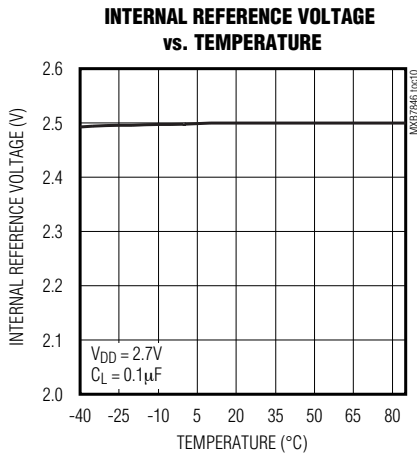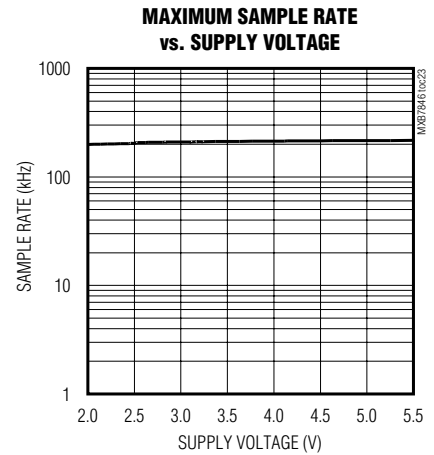
(V_{DD} = 2.7V, V_{REF} = 2.5$V_{EXTERNAL}$, f_{DCLK} = 2MHz, f_{SAMPLE} = 125kHz, C_{LOAD} = 50pF, 0.1µF capacitor at REF, T_A = +25°C, unless otherwise noted.)

INTERNAL REFERENCE VOLTAGE vs. TEMPERATURE

V_{DD} = 2.7V
C_L = 0.1µF

INTERNAL VOLTAGE REFERENCE vs. TURN-ON TIME

C_L = 1µF
(1060µs) 12-BIT SETTLING

INTERNAL VOLTAGE REFERENCE vs. TURN-ON TIME

NO CAPACITOR
(30µs) 12-BIT SETTLING

REFERENCE CURRENT vs. SUPPLY VOLTAGE

C_L = 0.1µF
f_{SAMPLE} = 125kHz
EXTERNAL REFERENCE

REFERENCE CURRENT vs. TEMPERATURE

V_{DD} = 2.7V
C_L = 0.1µF
f_{SAMPLE} = 125kHz
EXTERNAL REFERENCE

REFERENCE CURRENT vs. SAMPLE RATE

EXTERNAL REFERENCE

TEMP DIODE VOLTAGE vs. TEMPERATURE

TEMP1
TEMP2

TEMP0 DIODE VOLTAGE vs. SUPPLY VOLTAGE

TEMP0

TEMP1 DIODE VOLTAGE vs. SUPPLY VOLTAGE

TEMP1

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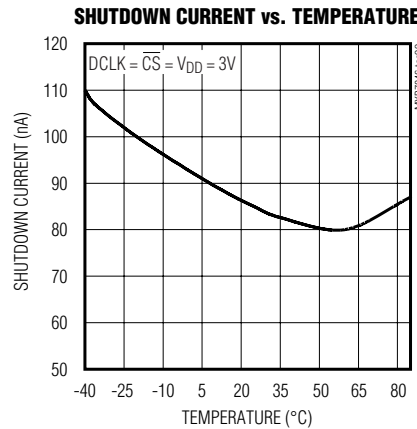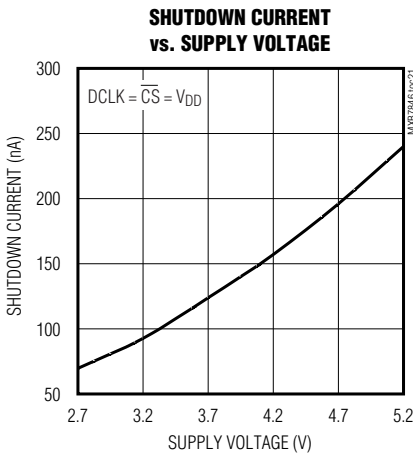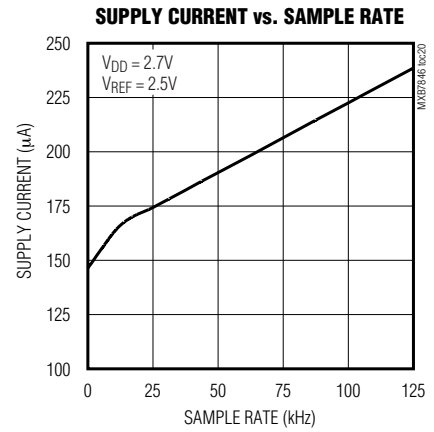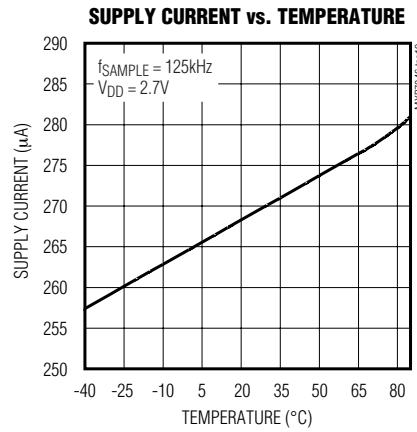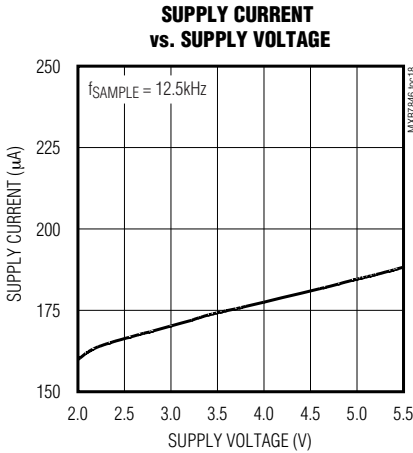
_____Typical Operating Characteristics (continued)

(V_{DD} = 2.7V, V_{REF} = 2.5$V_{EXTERNAL}$, f_{DCLK} = 2MHz, f_{SAMPLE} = 125kHz, C_{LOAD} = 50pF, 0.1µF capacitor at REF, T_A = +25°C, unless otherwise noted.)

SUPPLY CURRENT vs. SUPPLY VOLTAGE

SUPPLY CURRENT vs. TEMPERATURE

SUPPLY CURRENT vs. SAMPLE RATE

SHUTDOWN CURRENT vs. SUPPLY VOLTAGE

SHUTDOWN CURRENT vs. TEMPERATURE

MAXIMUM SAMPLE RATE vs. SUPPLY VOLTAGE

2.375V to 5.25V, 4-Wire Touch-Screen Controller with Internal Reference and Temperature Sensor

_____*Pin Description*

| PIN	NAME	FUNCTION
1	V$_{DD}$	Positive Supply Voltage. Connect to pin 10.
2	X+	X+ Position Input, ADC Input Channel 1
3	Y+	Y+ Position Input, ADC Input Channel 2
4	X-	X- Position Input
5	Y-	Y- Position Input
6	GND	Ground
7	BAT	Battery Monitoring Inputs; ADC Input Channel 3
8	AUX	Auxiliary Input to ADC; ADC Input Channel 4
9	REF	Voltage Reference Output/Input. Reference voltage for analog-to-digital conversion. In internal reference mode, the reference buffer provides a 2.50V nominal output. In external reference mode, apply a reference voltage between 1V and V$_{DD}$. Bypass REF to GND with a 0.1µF capacitor.
10	V$_{DD}$	Positive Supply Voltage, +2.375V (2.70V) to +5.25V. External (internal) reference. Bypass with a 1µF capacitor. Connect to pin 1.
11	$\overline{PENIRQ}$	Pen Interrupt Output. Open anode output. 10kΩ to 100kΩ pullup resistor required to V$_{DD}$.
12	DOUT	Serial Data Output. Data changes state on the falling edge of DCLK. High impedance when $\overline{CS}$ is HIGH.
13	BUSY	Busy Output. BUSY pulses high for one clock period before the MSB decision. High impedance when $\overline{CS}$ is HIGH.
14	DIN	Serial Data Input. Data clocked in on the rising edge of DCLK.
15	$\overline{CS}$	Active-Low Chip Select. Data is only clocked into DIN when $\overline{CS}$ is low. When $\overline{CS}$ is HIGH, DOUT and BUSY are high impedance.
16	DCLK	Serial Clock Input. Clocks data in and out of the serial interface and sets the conversion speed (duty cycle must be 40% to 60%).
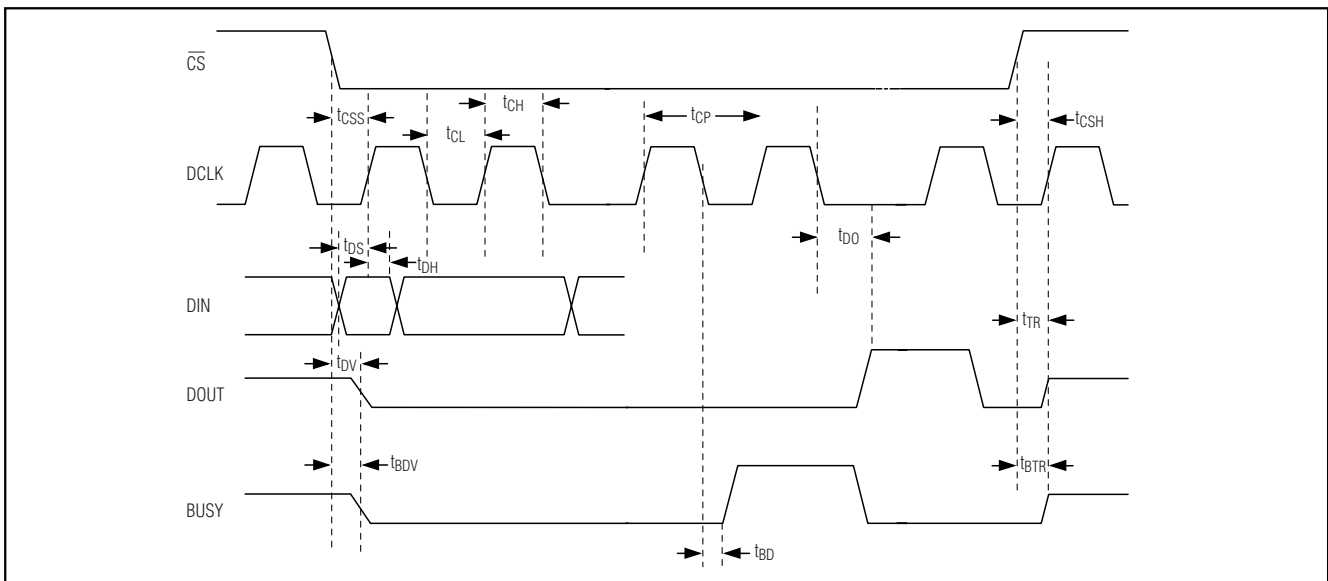
Figure 1. Detailed Serial Interface Timing

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2.375V to 5.25V, 4-Wire Touch-Screen Controller with Internal Reference and Temperature Sensor

Detailed Description

The MXB7846 uses a successive-approximation conversion technique to convert analog signals to a 12-bit digital output. An SPI/QSPI/MICROWIRE™-compatible serial interface provides easy communication to a microprocessor (µP). It features an internal 2.5V reference, an on-chip temperature sensor, a battery monitor, and a 4-wire touch-screen interface (*Functional Diagram*).

Analog Inputs

Figure 2 shows a block diagram of the analog input section that includes the input multiplexer of the MXB7846, the differential signal inputs of the ADC, and the differential reference inputs of the ADC. The input multiplexer switches between X+, X-, Y+, Y-, AUX, BAT, and the internal temperature sensor.

In single-ended mode, conversions are performed using REF as the reference. In differential mode, ratiometric conversions are performed with REF+ connected to X+ or Y+, and REF- connected to X- or Y-. Configure the reference and switching matrix according to Tables 1 and 2.

During the acquisition interval, the selected channel charges the sampling capacitance. The acquisition interval starts on the fifth falling clock edge and ends on the eighth falling clock edge.

The time required for the T/H to acquire an input signal is a function of how quickly its input capacitance is charged. If the input signal's source impedance is high, the acquisition time lengthens, and more time must be allowed between conversions. The acquisition time (t_{ACQ}) is the maximum time the device takes to acquire the input signal to 12-bit accuracy. Calculate t_{ACQ} with the following equation:

$$t_{ACQ} = 8.4 \times \left(R_S + R_{IN}\right) \times 25pF$$

where $R_{IN} = 2k\Omega$ and R_S is the source impedance of the input signal.

Source impedances below 1kΩ do not significantly affect the ADC's performance. Accommodate higher source impedances by either slowing down DCLK or by placing a 1µF capacitor between the analog input and GND.
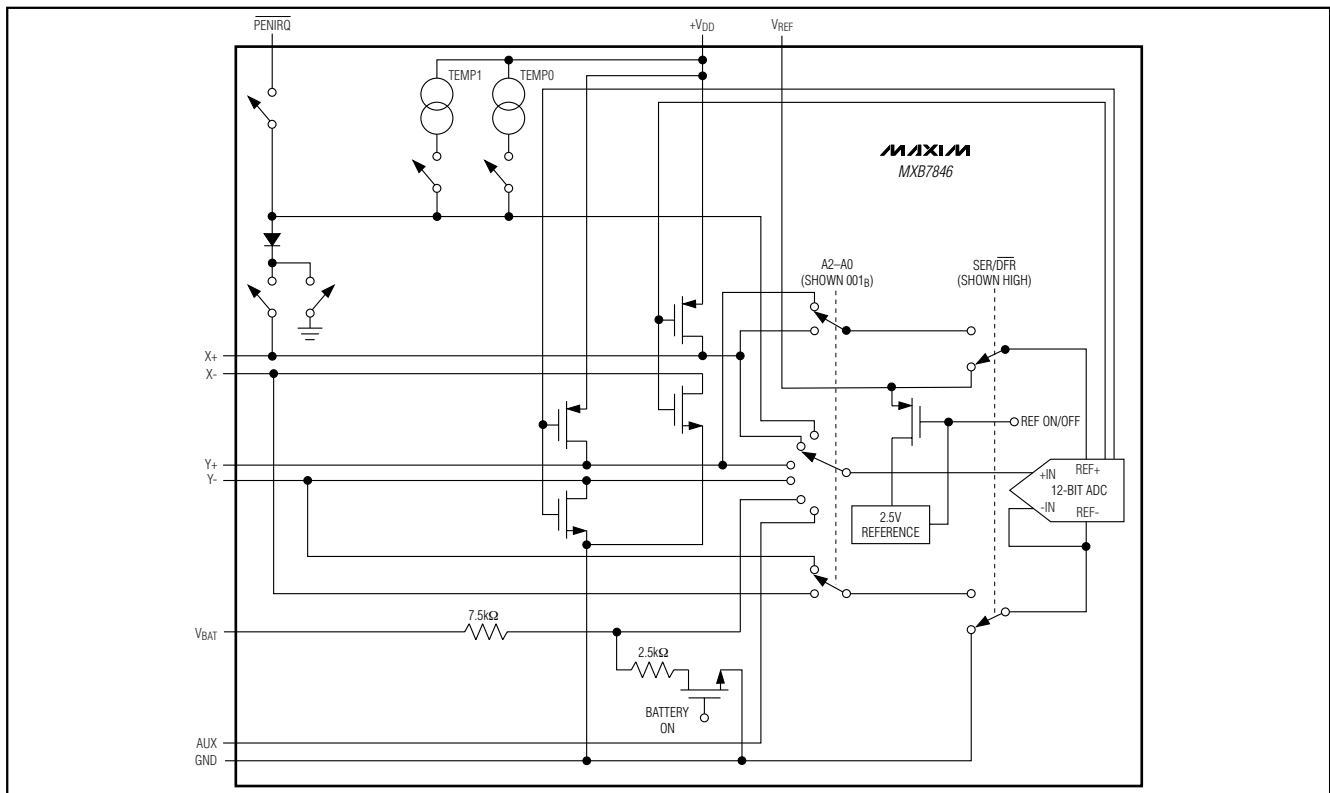

Figure 2. Equivalent Input Circuit

MICROWIRE is a trademark of National Semiconductor Corp.

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2.375V to 5.25V, 4-Wire Touch-Screen Controller with Internal Reference and Temperature Sensor
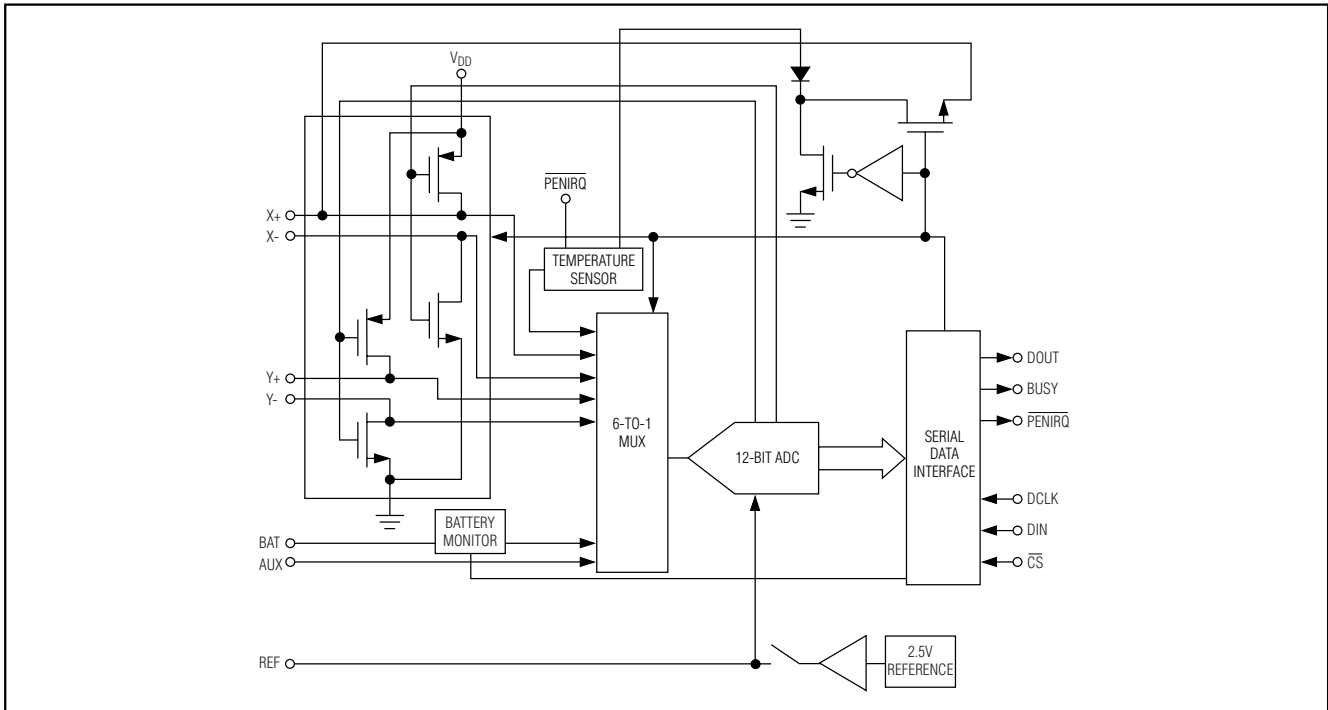
Table 1. Input Configuration, Single-Ended Reference Mode (SER/$\overline{\text{DFR}}$ HIGH)

A2	A1	A0	MEASUREMENT	ADC INPUT CONNECTION	DRIVERS ON
0	0	0	Temp0	Temp0	—
0	0	1	Y position	X+	Y+, Y-
0	1	0	BAT	BAT	—
0	1	1	Z1	X+	X-, Y+
1	0	0	Z2	Y-	X-, Y+
1	0	1	X- position	Y+	X-, X+
1	1	0	AUX	AUX	—
1	1	1	Temp1	Temp1	—

Table 2. Input Configuration, Differential Reference Mode (SER/$\overline{\text{DFR}}$ LOW)

A2	A1	A0	ADC +REF CONNECTION TO	ADC -REF CONNECTION TO	ADC INPUT CONNECTION TO	MEASUREMENT PERFORMED	DRIVER ON
0	0	1	Y+	Y-	X+	Y position	Y+, Y-
0	1	1	Y+	Y-	X+	Z1 position	Y+, X-
0	1	0	X+	X-	Y-	Z2 position	Y+, X-
1	0	1	X+	X-	Y+	X position	X+, X-

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MXB7846

Input Bandwidth and Anti-Aliasing

The ADCs input tracking circuitry has a 25MHz small-signal bandwidth, so it is possible to digitize high-speed transient events. To avoid high-frequency signals being aliased into the frequency band of interest, anti-alias filtering is recommended.

Analog Input Protection

Internal protection diodes, which clamp the analog input to V_{DD} and GND, allow the analog input pins to swing from GND - 0.3V to V_{DD} + 0.3V without damage. Analog inputs must not exceed V_{DD} by more than 50mV or be lower than GND by more than 50mV for accurate conversion. If an off-channel analog input voltage exceeds the supplies, limit the input current to 50mA. The analog input pins are ESD protected to ±8kV using the Contact Discharge method and ±15kV using the Air-Gap method specified in IEC 61000-4-2.

Touch-Screen Conversion

The MXB7846 provides two conversion methods—differential and single ended. The SER/$\overline{DFR}$ bit in the control word selects either mode. A logic 1 selects a single-ended conversion, while a logic 0 selects a differential conversion.

Differential vs. Single Ended

Changes in operating conditions can degrade the accuracy and repeatability of touch-screen measurements. Therefore, the conversion results representing X and Y coordinates may be incorrect. For example, in single-ended measurement mode, variation in the touch-screen driver voltage drops results in incorrect input reading. Differential mode minimizes these errors.

Single-Ended Mode

Figure 3 shows the switching matrix configuration for Y-coordinate measurement in single-ended mode. The MXB7846 measures the position of the pointing device by connecting X+ to IN+ of the ADC, enabling Y+ and Y- drivers, and digitizing the voltage on X+. The ADC performs a conversion with REF+ = REF and REF- = GND. In single-ended measurement mode, the bias to the touch screen can be turned off after the acquisition to save power. The on-resistance of the X and Y drivers results in a gain error in single-ended measurement mode. Touch-screen resistance ranges from 200Ω to 900Ω (depending on the manufacturer), whereas the on-resistance of the X and Y drivers is 8Ω (typ). Limit the touch-screen current to less than 50mA by using a touch screen with a resistance higher than 100Ω. The

resistive-divider created by the touch screen and the on-resistance of the X and Y drivers result in both an offset and a gain shift. Also, the on-resistance of the X and Y drivers does not track the resistance of the touch screen over temperature and supply. This results in further measurement errors.

Differential Measurement Mode

Figure 4 shows the switching matrix configuration for Y-coordinate measurement. The REF+ and REF- inputs are connected directly to the Y+ and Y- pins, respectively. Differential mode uses the voltage at the Y+ pin as the REF+ voltage and voltage at the Y- pin as REF- voltage. This conversion is ratiometric and independent of the voltage drop across the drivers and variation in the touch-screen resistance. In differential mode, the touch screen remains biased during the acquisition and conversion process. This results in additional supply current and power dissipation during conversion when compared to the absolute measurement mode.

PEN Interrupt Request ($\overline{PENIRQ}$)

Figure 5 shows the block diagram for the $\overline{PENIRQ}$ function. When used, $\overline{PENIRQ}$ requires a 10kΩ to 100kΩ pullup to +V_{DD}. If enabled, $\overline{PENIRQ}$ goes low whenever the touch screen is touched. The $\overline{PENIRQ}$ output can be used to initiate an interrupt to the microprocessor, which can write a control word to the MXB7846 to start a conversion.

Figure 6 shows the timing diagram for the $\overline{PENIRQ}$ pin function. The diagram shows that once the screen is touched while $\overline{CS}$ is high, the $\overline{PENIRQ}$ output goes low after a time period indicated by t_{TOUCH}. The t_{TOUCH} value changes for different touch-screen parasitic capacitance and resistance. The microprocessor receives this interrupt and pulls $\overline{CS}$ low to initiate a conversion. At this instant, the $\overline{PENIRQ}$ pin should be masked, as transitions can occur due to a selected input channel or the conversion mode. The $\overline{PENIRQ}$ pin functionality becomes valid when either the last data bit is clocked out, or $\overline{CS}$ is pulled high.

Touch-Pressure Measurement

The MXB7846 provides two methods for measuring the pressure applied to the touch screen (Figure 7). By measuring R_{TOUCH}, it is possible to differentiate between a finger or stylus in contact with the touch screen. Although 8-bit resolution is typically sufficient, the following calculations use 12-bit resolution demonstrating the maximum precision of the MXB7846.
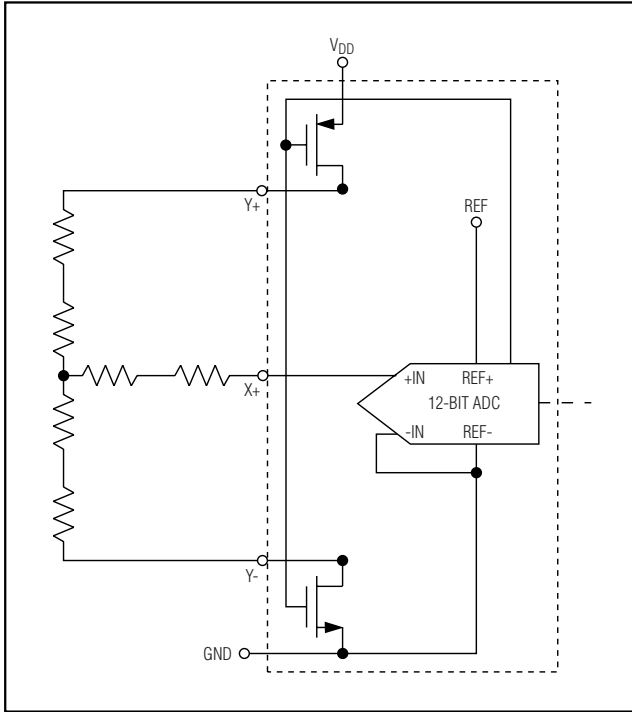
MXB7846

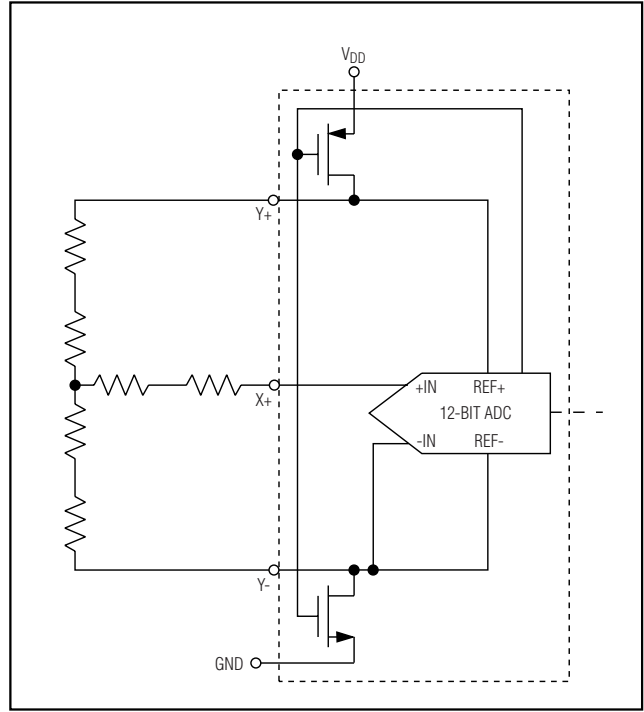Figure 3. Single-Ended Y-Coordinate Measurement

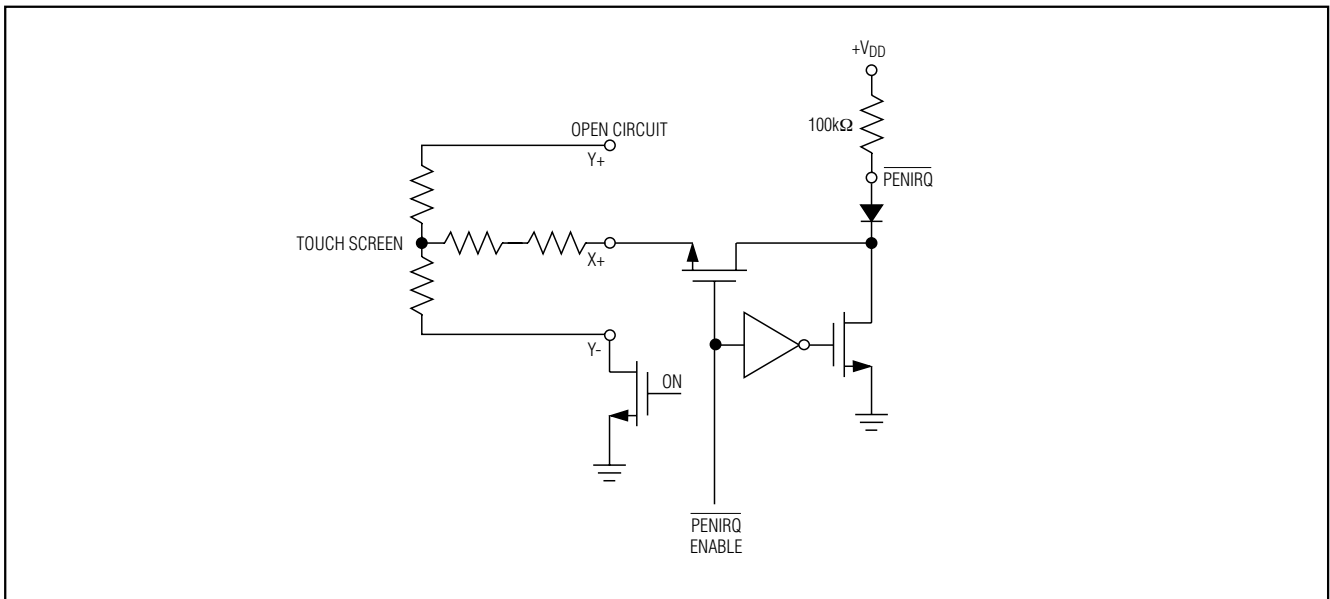Figure 4. Ratiometric Y-Coordinate Measurement

Figure 5. $\overline{PENIRQ}$ Functional Block Diagram

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2.375V to 5.25V, 4-Wire Touch-Screen Controller with Internal Reference and Temperature Sensor
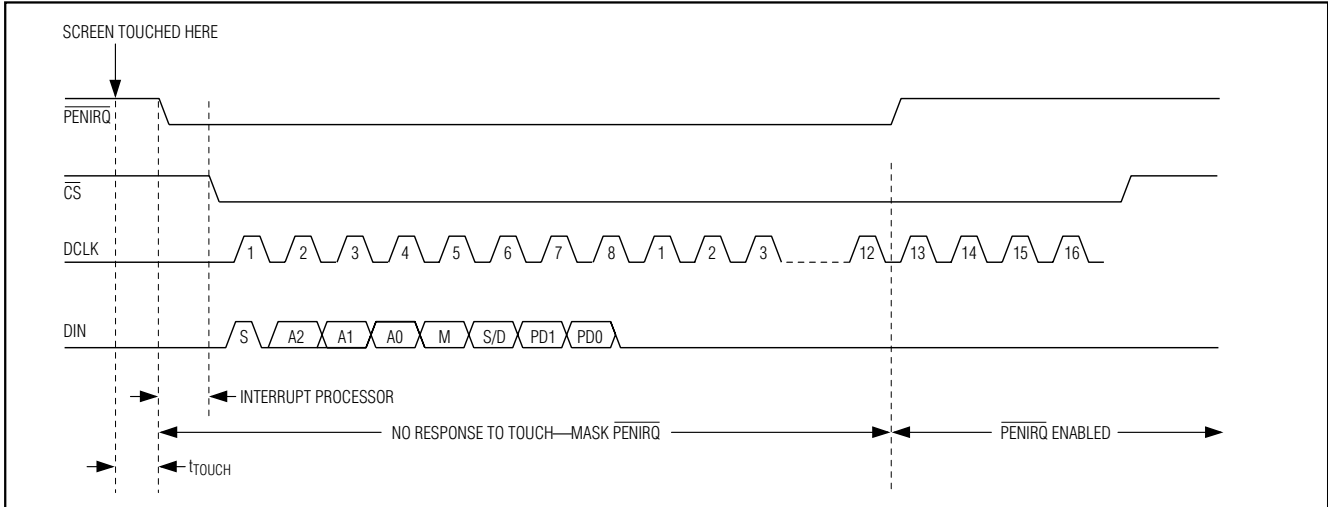

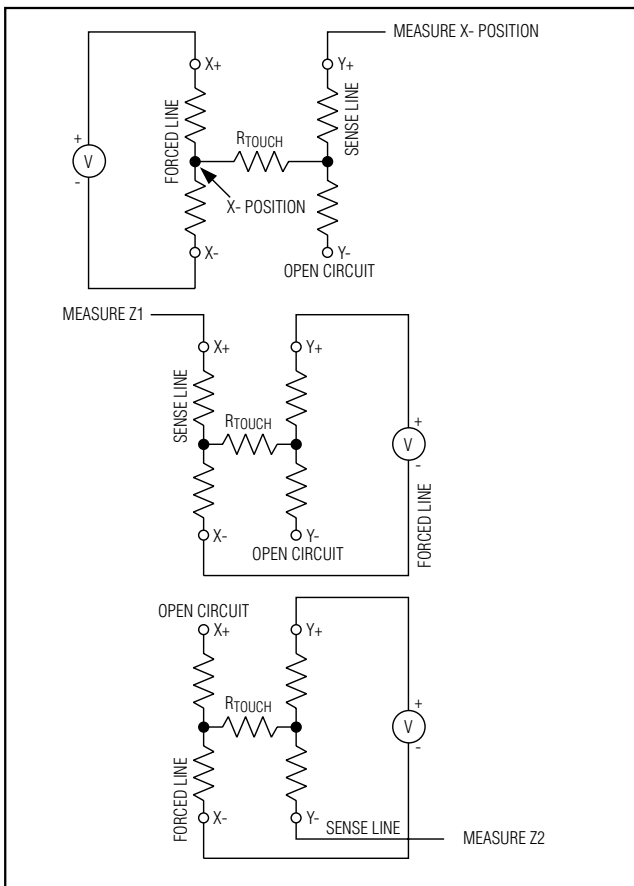*Figure 6. $\overline{PENIRQ}$ Timing Diagram*

Figure 7. Pressure Measurement Block Diagram

The first method performs pressure measurements using a known X-plate resistance. After completing three conversions (X-position, Z1, and Z2), use the following equation to calculate R_{TOUCH}:

$$R_{TOUCH} = \left(R_{XPLATE}\right) \times \left(\frac{X_{POSITION}}{4096}\right) \times \left[\left(\frac{Z_2}{Z_1}\right) - 1\right]$$

The second method requires knowing both the X-plate and Y-plate resistance. Three conversions are required in this method: the X-position, Y-position, and Z1-position. Use the following equation to calculate R_{TOUCH}:

$$R_{TOUCH} = \left\{\left(\frac{R_{XPLATE}}{Z_1}\right) \times \left(\frac{X_{POSITION}}{4096}\right) \times \left[\left(\frac{4096}{Z_1}\right) - 1\right] \right. $$
$$\left. - \left\{R_{YPLATE} \times \left(\frac{Y_{POSITION}}{4096}\right)\right\}\right\}$$

Internal Temperature Sensor

The MXB7846 provides two temperature measurement options: single-ended conversion and differential conversion. Both temperature measurement techniques rely on the semiconductor junction's temperature characteristics. The forward diode voltage (V_{BE}) vs. temperature is a well-defined characteristic. The ambient temperature can be calculated by knowing the value of V_{BE} at a fixed temperature and then monitoring the change in that voltage as the temperature changes. The single conversion method requires calibration at a known temperature, but only needs a single reading to calculate the ambient temperature. First, the $\overline{PENIRQ}$ diode for-

/WIXIW

ward bias voltage is measured by the ADC with an address of A2 = 0, A1 = 0, and A0 = 0 at a known temperature. Subsequent diode measurements provide an estimate of the ambient temperature through extrapolation. This assumes a temperature coefficient of -2.1mV/°C. The single conversion method results in a resolution of 0.3°C/LSB and a typical accuracy of ±3°C.

The differential conversion method uses two measurement points. The first measurement (Temp0) is performed with a fixed bias current into the $\overline{PENIRQ}$ diode. The second measurement (Temp1) is performed with a fixed multiple of the original bias current with an address of A2 = 1, A1 = 1, and A0 = 1. The voltage difference between the first and second conversion is proportional to the absolute temperature and is expressed by the following formula:

$$T(°C) = \left[2.60 \times (T1 - T0)\left(\frac{VREF}{4096}\right) \times 1000 \right] - 273$$

where T0 (Temp0) and T1 (Temp1) are the conversion results.

This differential conversion method can provide much improved absolute temperature measurement; however, the resolution is reduced to 1.6°C/LSB.

Battery Voltage Monitor
A dedicated analog input (BAT) allows the MXB7846 to monitor the system battery voltage. Figure 8 shows the battery voltage monitoring circuitry. The MXB7846 monitors battery voltages from 0 to 6V. An internal resistor network divides down V_{BAT} by 4 so that a 6.0V battery voltage results in 1.5V at the ADC input. To minimize power consumption, the divider is only enabled during the sampling of V_{BAT}.

Internal Reference
Enable the internal 2.5V reference by setting PD1 in the control byte to a logic 1 (see Tables 3 and 4). The MXB7846 uses the internal reference for single-ended measurement mode, battery monitoring, temperature measurement, and for measurement on the auxiliary input. To minimize power consumption, disable the internal reference by setting PD1 to a logic 0 when performing ratiometric position measurements. The internal 2.5V reference typically requires 10ms to settle (with no external load). For optimum performance, connect a 0.1µF capacitor from REF to GND. This internal reference can be overdriven with an external reference. For best performance, the internal reference should be disabled when the external reference is applied. The internal reference of the MXB7846 must also be disabled to maintain compatibility with the MXB7843. To disable the internal reference of the MXB7846 after power-up, a control byte with PD1 = 0 is required. (See *Typical Operating Characteristics* for power-up time of the reference from power down.)

External Reference
Although the internal reference may be overdriven with an external reference, the internal reference should be disabled (PD1 = 0) for best performance when using an external reference. During conversion, an external reference at REF must deliver up to 40µA DC load current. If the reference has a higher output impedance or is noisy, bypass it close to the REF pin with a 0.1µF and a 4.7µF capacitor. Temperature measurements are always performed using the internal reference.

Digital Interface
Initialization After Power-Up and Starting a Conversion
The digital interface consists of three inputs, DIN, DCLK, $\overline{CS}$, and one output, DOUT. A logic-high on $\overline{CS}$ disables the MXB7846 digital interface and places DOUT in a high-impedance state. Pulling $\overline{CS}$ low enables the MXB7846 digital interface.
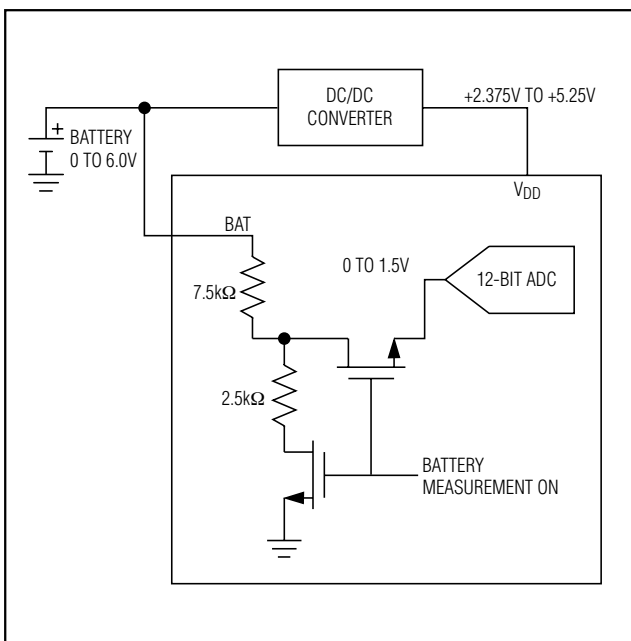

Figure 8. Battery Measurement Functional Block Diagram

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Table 3. Control Byte Format

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
START	A2	A1	A0	MODE	SER/$\overline{\text{DFR}}$	PD1	PD0

BIT	NAME	DESCRIPTION
7	START	Start bit
6	A2	Address (Tables 1 and 2)
5	A1	
4	A0	
3	MODE	Conversion resolution: 1 = 8 bits, 0 = 12 bits
2	SER/$\overline{\text{DFR}}$	Conversion mode: 1 = single ended, 0 = differential
1	PD1	Power-down mode (Table 4)
0	PD0	

Start a conversion by clocking a control byte into DIN (Table 3) with $\overline{\text{CS}}$ low. Each rising edge on DCLK clocks a bit from DIN into the MXB7846's internal shift register. After $\overline{\text{CS}}$ falls, the first arriving logic 1 bit defines the control byte's START bit. Until the START bit arrives, any number of logic 0 bits can be clocked into DIN with no effect.

The MXB7846 is compatible with SPI/QSPI/MICROWIRE devices. For SPI, select the correct clock polarity and sampling edge in the SPI control registers of the micro-controller: set CPOL = 0 and CPHA = 0. MICROWIRE, SPI, and QSPI all transmit a byte and receive a byte at the same time. The simplest software interface requires only three 8-bit transfers to perform a conversion (one 8-bit transfer to configure the ADC, and two more 8-bit transfers to read the conversion result; Figure 9).

Simple Software Interface
Make sure the CPU's serial interface runs in master mode so the CPU generates the serial clock. Choose a clock frequency from 500kHz to 2MHz:

1) Set up the control byte and call it TB. TB should be in the format: 1XXXXXXX binary, where X denotes the particular channel, selected conversion mode, and power mode (Tables 3, 4).

2) Use a general-purpose I/O line on the CPU to pull $\overline{\text{CS}}$ low.

3) Transmit TB and simultaneously receive a byte; call it RB1.

4) Transmit a byte of all zeros ($00 hex) and simultaneously receive byte RB2.

5) Transmit a byte of all zeros ($00 hex) and simultaneously receive byte RB3.

6) Pull $\overline{\text{CS}}$ high.

Figure 9 shows the timing for this sequence. Byte RB2 and RB3 contain the result of the conversion, padded with four trailing zeros. The total conversion time is a function of the serial-clock frequency and the amount of idle timing between 8-bit transfers.

Digital Output
The MXB7846 outputs data in straight binary format. Data is clocked out on the falling edge of the DCLK MSB first.

Serial Clock
The external clock not only shifts data in and out, but it also drives the analog-to-digital conversion steps. BUSY pulses high for one clock period after the last bit of the control byte. Successive-approximation bit deci-sions are made and appear at DOUT on each of the next 12 DCLK falling edges. BUSY and DOUT go into a high-impedance state when $\overline{\text{CS}}$ goes high.

The conversion must complete in 500µs or less; if not, droop on the sample-and-hold capacitors can degrade conversion results.

Data Framing
The falling edge of $\overline{\text{CS}}$ does not start a conversion. The first logic high clocked into DIN is interpreted as a start bit and defines the first bit of the control byte. A conversion starts on DCLK's falling edge, after the eighth bit of the control byte is clocked into DIN.

The first logic 1 clocked into DIN after bit 6 of a conversion in progress is clocked onto the DOUT pin and is treated as a START bit (Figure 10).

Once a start bit has been recognized, the current conversion must be completed.

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Table 4. Power-Mode Selection

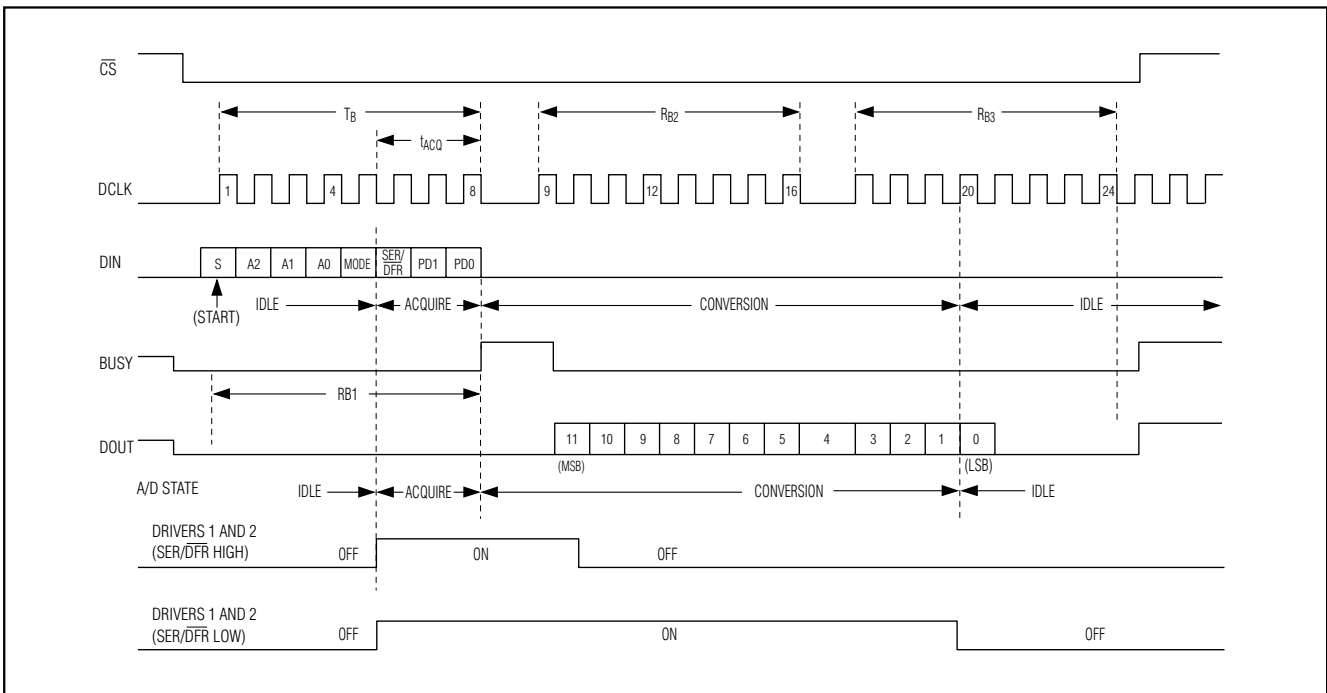| PD1	PD0	$\overline{PENIRQ}$	STATUS	SUPPLY CURRENT (typ) (µA)	
				DURING CONVERSION	AFTER CONVERSION
0	0	Enabled	ADC is ON during conversion, OFF between conversion	200	1
0	1	Disabled	ADC is always ON, reference is always OFF	200	200
1	0	Disabled	ADC is always OFF, reference is always ON	400	400
1	1	Disabled	ADC is always ON, reference is always ON	600	600

Figure 9. Conversion Timing, 24-Clock per Conversion, 8-Bit Bus Interface

The fastest the MXB7846 can run with $\overline{CS}$ held continuously low is 15 clock conversions. Figure 10 shows the serial-interface timing necessary to perform a conversion every 15 DCLK cycles. If $\overline{CS}$ is connected low and DCLK is continuous, guarantee a start bit by first clocking in 16 zeros.

Most microcontrollers (µCs) require that data transfers occur in multiples of eight DCLK cycles; 16 clocks per conversion is typically the fastest that a µC can drive the MXB7846. Figure 11 shows the serial interface timing necessary to perform a conversion every 16 DCLK cycles.

8-Bit Conversion

The MXB7846 provides an 8-bit conversion mode selected by setting the MODE bit in the control byte high. In the 8-bit mode, conversions complete four clock cycles earlier than in the 12-bit output mode, resulting in 25% faster throughput. This can be used in conjunction with serial interfaces that provide 12-bit transfers, or two conversions could be accomplished with three 8-bit transfers. Not only does this shorten each conversion by 4 bits, but each conversion can also occur at a faster clock rate since settling to better than 8 bits is all that is required. The clock rate can be as much as 25% faster. The faster clock rate and fewer clock cycles combine to increase the conversion rate.

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Data Format

The MXB7846 output data is in straight binary format as shown in Figure 12. This figure shows the ideal output code for the given input voltage and does not include the effects of offset, gain, or noise.

Applications Information

Basic Operation of the MXB7846

The 4-wire touch-screen controller works by creating a voltage gradient across the vertical or horizontal resistive network connected to the MXB7846, as shown in the *Typical Application Circuit*. The touch screen is biased through internal MOSFET switches that connect each resistive layer to V_{DD} and ground on an alternate basis. For example, to measure the Y position when a pointing device presses on the touch screen, the Y+

and Y- drivers are turned on, connecting one side of the vertical resistive layer to V_{DD} and the other side to ground. In this case, the horizontal resistive layer functions as a sense line. One side of this resistive layer gets connected to the X+ input, while the other side is left open or floating. The point where the touch screen is pressed brings the two resistive layers in contact and forms a voltage-divider at that point. The data converter senses the voltage at the point of contact through the X+ input and digitizes it. The horizontal layer resistance does not introduce any error in the conversion because no DC current is drawn.

The conversion process of the analog input voltage to digital output is controlled through the serial interface between the A/D converter and the µP. The processor controls the MXB7846 configuration through a control byte (see Tables 3 and 4). Once the processor instructs
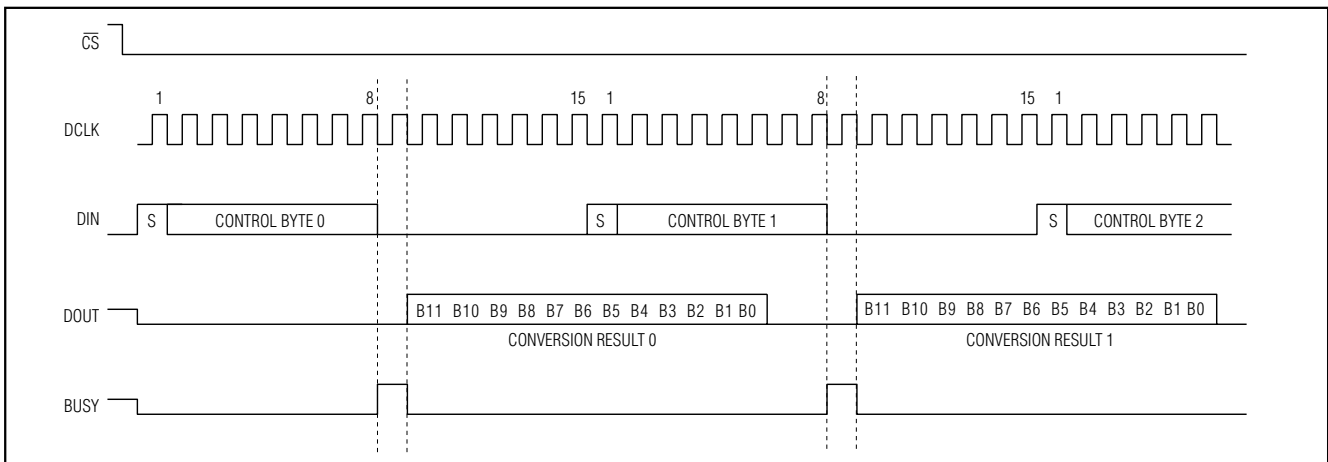

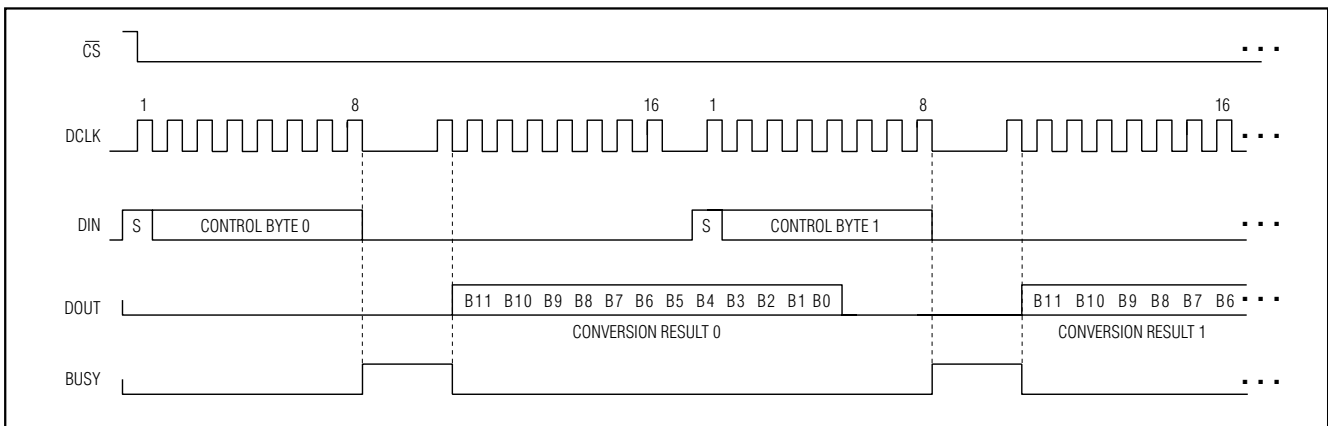*Figure 10. 15-Clock/Conversion Timing*

Figure 11. 16-Clock/Conversion Timing

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the MXB7846 to initiate a conversion, the MXB7846 biases the touch screen through the internal switches at the beginning of the acquisition period. The voltage transient at the touch screen needs to settle down to a stable voltage before the acquisition period is over. After the acquisition period is over, the A/D converter goes into a conversion period with all internal switches turned off if the device is in single-ended mode. If the device is in differential mode, the internal switches remain on from the start of the acquisition period to the end of the conversion period.

Power-On Reset

When power is first applied, internal power-on circuitry resets the MXB7846. Allow 10µs for the first conversion after the power supplies stabilize. If $\overline{CS}$ is low, the first logic 1 on DIN is interpreted as a start bit. Until a conversion takes place, DOUT shifts out zeros. On power-up, allow time for the reference to stabilize.

Power Modes

Save power by placing the converter in one of two low-current operating modes or in full power down between conversions. Select the power-down mode through PD1 and PD0 of the control byte (Tables 3 and 4).

The software power-down modes take effect after the conversion is completed. The serial interface remains active while waiting for a new control byte to start a conversion and switches to full-power mode. After completing its conversion, the MXB7846 enters the programmed power mode until a new control byte is received.
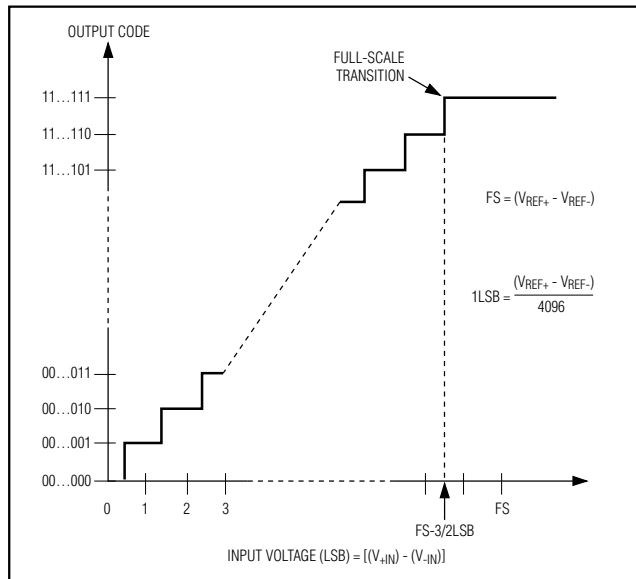

Figure 12. Ideal Input Voltages and Output Codes

The power-up wait before conversion period is dependent on the power-down state. When exiting software low-power modes, conversion can start immediately when running at decreased clock rates. Upon power-on reset, the MXB7846 is in power-down mode with PD1 = 0 and PD0 = 0. When exiting software shutdown, the MXB7846 is ready to perform a conversion in 10µs with an external reference. When using the internal reference, allow enough time for reference to settle to 12-bit accuracy when exiting full power-down mode, as shown in the *Typical Operating Characteristics*.

PD1 = 1, PD0 = 1

In this mode, the MXB7846 is always powered up and both the reference and the ADC are always on. The device remains fully powered after the current conversion completes.

PD1 = 0, PD0 = 0

In this mode, the MXB7846 powers down after the current conversion completes or on the next rising edge of $\overline{CS}$, whichever occurs first. The next control byte received on DIN powers up the MXB7846. At the start of a new conversion, it instantly powers up. When each conversion is finished, the part enters power-down mode, unless otherwise indicated. The first conversion after the ADC returns to full power is valid for differential conversions and single-ended measurement conversions when using an external reference.

When operating at full speed and 16 clocks per conversion, the difference in power consumption between PD1 = 0, PD0 = 1, and PD1 = 0, PD0 = 0 is negligible. Also, in the case where the conversion rate is decreased by slowing the frequency of the DCLK input, the power consumption between these two modes is not very different. When the DCLK frequency is kept at the maximum rate during a conversion, conversions are done less often. There is a significant difference in power consumption between these two modes.

PD1 = 1, PD0 = 0

In this mode, the MXB7846 is powered down. This mode becomes active after the current conversion completes or on the next rising edge of $\overline{CS}$, whichever occurs first. The next command byte received on the DIN returns the MXB7846 to full power. The first conversion after the ADC returns to full power is valid.

PD1 = 0, PD0 = 1

This mode turns the internal reference off and leaves the ADC on to perform conversions using an external reference.

2.375V to 5.25V, 4-Wire Touch-Screen Controller with Internal Reference and Temperature Sensor

Hardware Power-Down

$\overline{CS}$ also places the MXB7846 into power-down. When $\overline{CS}$ goes HIGH, the MXB7846 immediately powers down and aborts the current conversion. The internal reference does not turn off when $\overline{CS}$ goes high. To disable the internal reference, an additional command byte is required before $\overline{CS}$ goes high (PD1 = 0). Set PD1 = 0 before $\overline{CS}$ goes high.

Touch-Screen Settling

There are two key touch-screen characteristics that can degrade accuracy. First, the parasitic capacitance between the top and bottom layers of the touch screen can result in electrical ringing. Second, vibration of the top layer of the touch screen can cause mechanical contact bouncing.

External filter capacitors may be required across the touch screen to filter noise induced by the LCD panel or backlight circuitry, etc. These capacitors lengthen the settling time required when the panel is touched and can result in a gain error, as the input signal may not settle to its final steady-state value before the ADC samples the inputs. Two methods to minimize or eliminate this issue are described below.

One option is to lengthen the acquisition time by stopping or slowing down DCLK, allowing for the required touch-screen settling time. This method solves the settling time problem for both single-ended and differential modes.

The second option is to operate the MXB7846 in the differential mode only for the touch screen, and perform additional conversions with the same address until the input signal settles. The MXB7846 can then be placed in the power-down state on the last measurement.

Connection to Standard Interface

MICROWIRE Interface

When using the MICROWIRE- (Figure 13) or SPI-compatible interface (Figure 14), set the CPOL = CPHA = 0. Two consecutive 8-bit readings are necessary to obtain the entire 12-bit result from the ADC. DOUT data transitions occur on the serial clock's falling edge and are clocked into the µP on the DCLK's rising edge. The first 8-bit data stream contains the first 8 bits of the current conversion, starting with the MSB. The second 8-bit data stream contains the remaining 4 result bits followed by 4 trailing zeros. DOUT then goes high impedance when $\overline{CS}$ goes high.

QSPI/SPI Interface

The MXB7846 can be used with the QSPI/SPI interface using the circuit in Figure 14 with CPOL = 0 and CPHA = 0. This interface can be programmed to do a conversion on any analog input of the MXB7846.
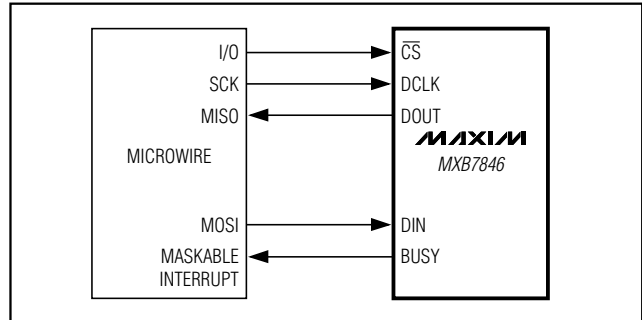
Figure 13. MICROWIRE Interface
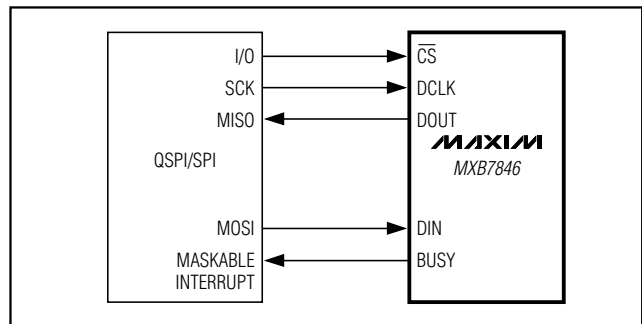
Figure 14. QSPI/SPI Interface
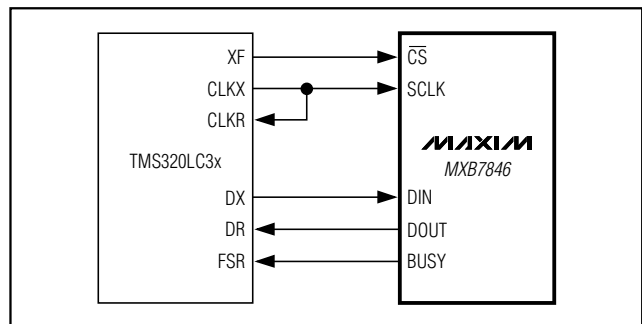
Figure 15. TMS320 Serial Interface

TMS320LC3x Interface

Figure 15 shows an example circuit to interface the MXB7846 to the TMS320. The timing diagram for this interface circuit is shown in Figure 16.

Use the following steps to initiate a conversion in the MXB7846 and to read the results:

1) The TMS320 should be configured with CLKX (transmit clock) as an active-high output clock and CLKR (TMS320 receive clock) as an active-high input clock. CLKX and CLKR on the TMS320 are connected to the MXB7846 DCLK input.

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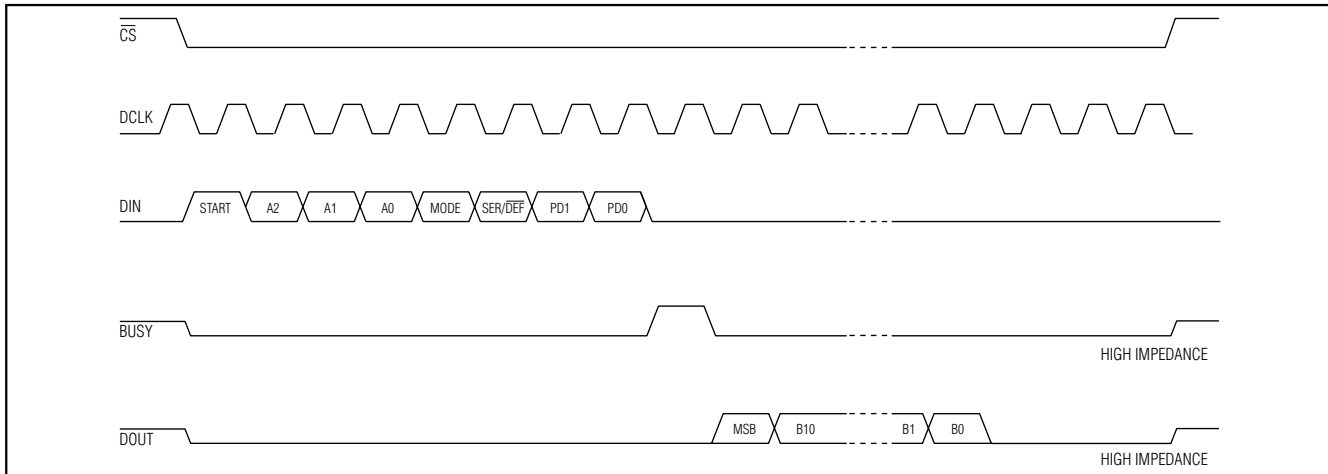
Figure 16. MXB7846-to-TMS320 Serial Interface Timing Diagram

2) The MXB7846's CS pin is driven low by the TMS320's XF I/O port to enable data to be clocked into the MXB7846's DIN pin.

3) An 8-bit word (1XXXXXXX) should be written to the MXB7846 to initiate a conversion and place the device into normal operating mode. See Table 3 to select the proper XXXXXXX bit values for your specific applications.

4) The MXB7846's BUSY output is monitored through the TMS320's FSR input. A falling edge on the BUSY output indicates that the conversion is in progress and data is ready to be received from the device.

5) The TMS320 reads in 1 data bit on each of the next 16 rising edges of DCLK. These bits represent the 12-bit conversion result followed by 4 trailing bits.

6) Pull CS high to disable the MXB7846 until the next conversion is initiated.

Layout, Grounding, and Bypassing
For best performance, use printed circuit (PC) boards with good layouts; wire-wrap boards are not recommended. Board layout should ensure that digital and analog signal lines are separated from each other. Do not run analog and digital (especially clock) lines parallel to one another, or digital lines underneath the ADC package.

Establish a single-point analog ground (star ground point) at GND. Connect all analog grounds to the star ground. Connect the digital system ground to the star ground at this point only. For lowest noise operation, minimize the length of the ground return to the star ground's power supply.

Power-supply decoupling is also crucial for optimal device performance. A good way to decouple analog supplies is to place a 10µF tantalum capacitor in parallel with a 0.1µF capacitor bypassed to GND. To maximize performance, place these capacitors as close as possible to the supply pin of the device. Minimize capacitor lead length for best supply-noise rejection. If the supply is very noisy, a 10Ω resistor can be connected in series as a lowpass filter.

While using the MXB7846, the interconnection between the converter and the touch screen should be as short as possible. Since touch screens have low resistance, longer or loose connections may introduce error. Noise can also be a major source of error in touch-screen applications (e.g., applications that require a backlight LCD panel). EMI noise coupled through the LCD panel to the touch screen may cause flickering of the converted data. Utilizing a touch screen with a bottom-side metal layer connected to ground decouples the noise to ground. In addition, the filter capacitors from Y+, Y-, X+, and X- inputs to ground also help further reduce the noise. Caution should be observed for settling time of the touch screen, especially operating in the single-ended measurement mode and at high data rates.

Definitions

Integral Nonlinearity
Integral nonlinearity (INL) is the deviation of the values on an actual transfer function from a straight line. This straight line can be either a best-straight-line fit or a line drawn between the endpoints of the transfer function, once offset and gain errors have been nullified. The static linearity parameters for the MXB7846 are measured using the end-point method.

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Differential Nonlinearity

Differential nonlinearity (DNL) is the difference between an actual step width and the ideal value of 1LSB. A DNL error specification of less than 1LSB guarantees no missing codes and a monotonic transfer function.

Aperture Jitter

Aperture jitter (t_{AJ}) is the sample-to-sample variation in the time between the samples.
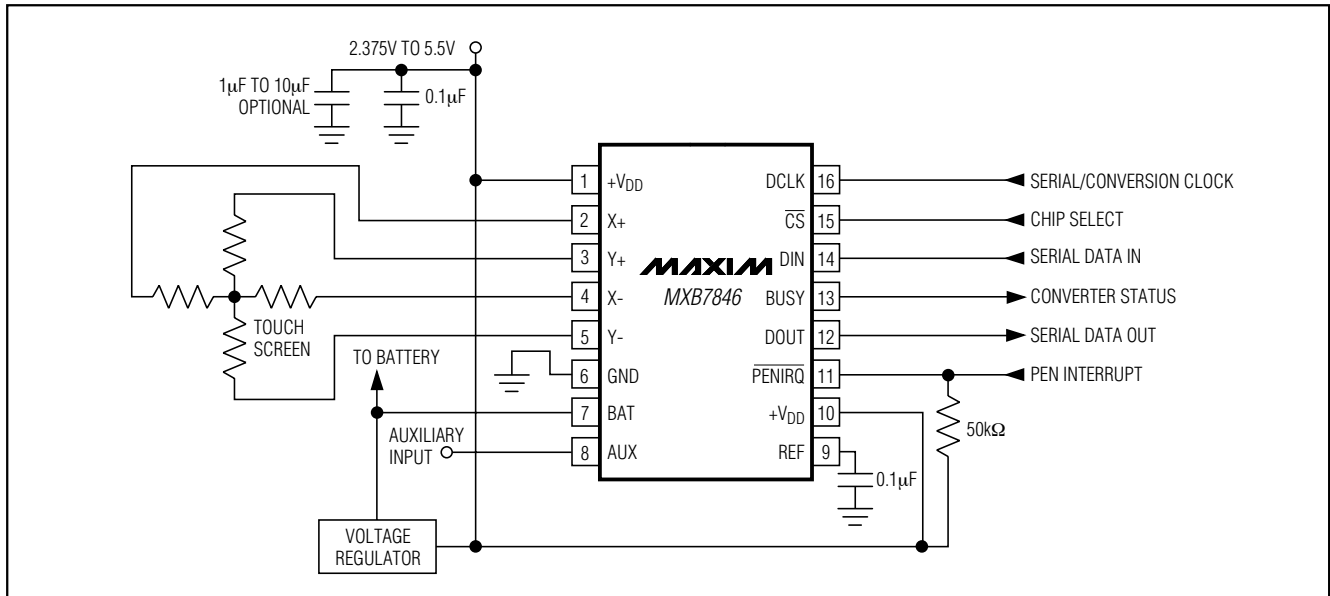
Aperture Delay

Aperture delay (t_{AD}) is the time defined between the falling edge of the sampling clock and the instant when an actual sample is taken.

Chip Information

TRANSISTOR COUNT: 12,000
PROCESS: 0.6μm BiCMOS

Typical Application Circuit

MXB7846

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)

QSOP.EPS

DIM	INCHES MIN	INCHES MAX	MILLIMETERS MIN	MILLIMETERS MAX
A	.061	.068	1.55	1.73
A1	.004	.0098	0.102	0.249
A2	.055	.061	1.40	1.55
B	.008	.012	0.20	0.30
C	.0075	.0098	0.191	0.249
D	SEE VARIATIONS			
E	.150	.157	3.81	3.99
e	.025 BSC		0.635 BSC	
H	.230	.244	5.84	6.20
h	.010	.016	0.25	0.41
L	.016	.035	0.41	0.89
N	SEE VARIATIONS			
α	0°	8°	0°	8°

VARIATIONS:

	INCHES MIN.	INCHES MAX.	MILLIMETERS MIN.	MILLIMETERS MAX.	N	
D	.189	.196	4.80	4.98	16	AB
S	.0020	.0070	0.05	0.18		
D	.337	.344	8.56	8.74	20	AD
S	.0500	.0550	1.270	1.397		
D	.337	.344	8.56	8.74	24	AE
S	.0250	.0300	0.635	0.762		
D	.386	.393	9.80	9.98	28	AF
S	.0250	.0300	0.635	0.762		

NOTES:
1). D & E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
2). MOLD FLASH OR PROTRUSIONS NOT TO EXCEED .006" PER SIDE.
3). CONTROLLING DIMENSIONS: INCHES.
4). MEETS JEDEC MO137.

DALLAS SEMICONDUCTOR /\/\/\/\XI/\/\
PROPRIETARY INFORMATION

TITLE:
PACKAGE OUTLINE, QSOP .150", .025" LEAD PITCH

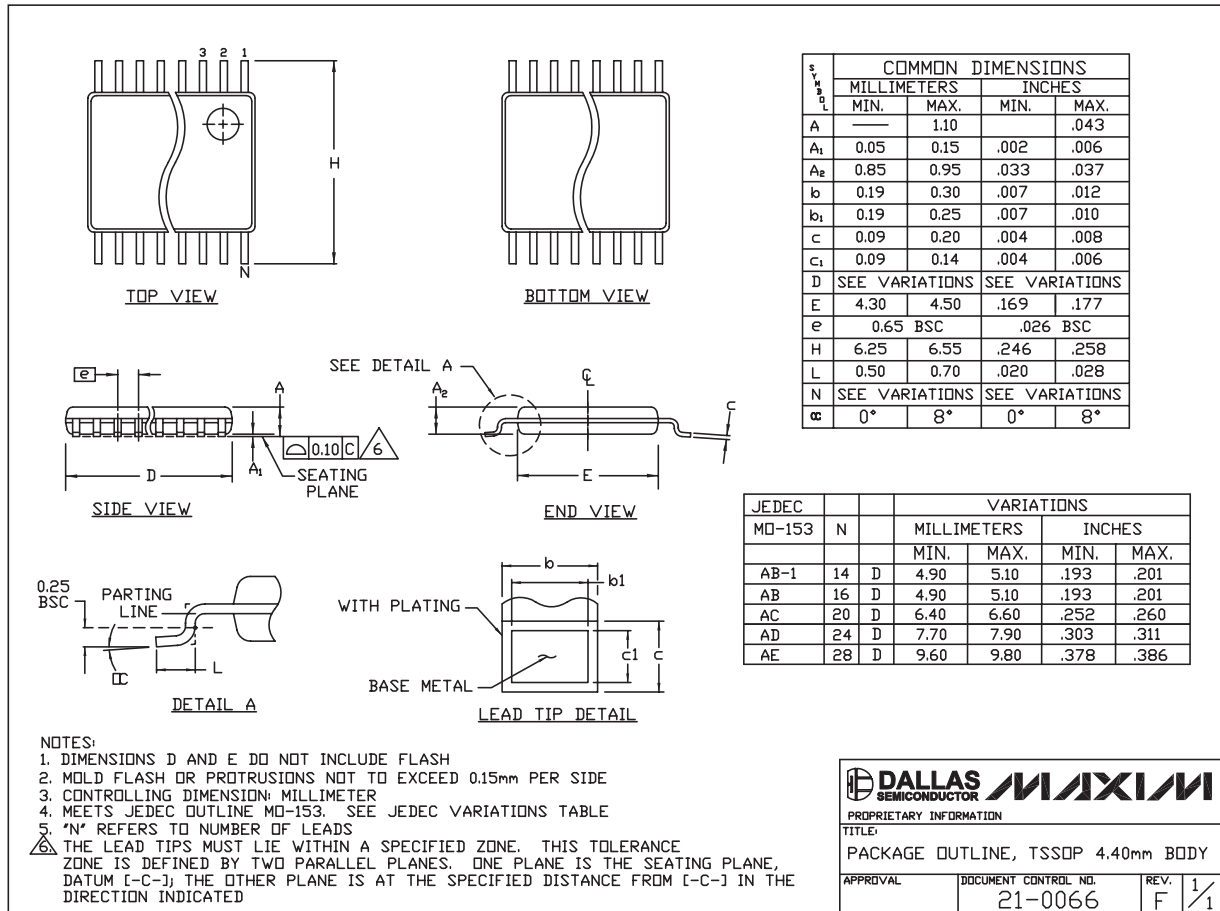| APPROVAL	DOCUMENT CONTROL NO.	REV.	
	21-0055	E	1/1

/\/\/\XI/\/\

Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)

TSSOP4.40mm.EPS

COMMON DIMENSIONS

SYMBOL	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	——	1.10		.043
A1	0.05	0.15	.002	.006
A2	0.85	0.95	.033	.037
b	0.19	0.30	.007	.012
b1	0.19	0.25	.007	.010
c	0.09	0.20	.004	.008
c1	0.09	0.14	.004	.006
D	SEE VARIATIONS		SEE VARIATIONS	
E	4.30	4.50	.169	.177
e	0.65 BSC		.026 BSC	
H	6.25	6.55	.246	.258
L	0.50	0.70	.020	.028
N	SEE VARIATIONS		SEE VARIATIONS	
α	0°	8°	0°	8°

VARIATIONS

JEDEC MO-153	N		MILLIMETERS		INCHES	
			MIN.	MAX.	MIN.	MAX.
AB-1	14	D	4.90	5.10	.193	.201
AB	16	D	4.90	5.10	.193	.201
AC	20	D	6.40	6.60	.252	.260
AD	24	D	7.70	7.90	.303	.311
AE	28	D	9.60	9.80	.378	.386

TOP VIEW · BOTTOM VIEW · SIDE VIEW · END VIEW · DETAIL A · LEAD TIP DETAIL

NOTES:
1. DIMENSIONS D AND E DO NOT INCLUDE FLASH
2. MOLD FLASH OR PROTRUSIONS NOT TO EXCEED 0.15mm PER SIDE
3. CONTROLLING DIMENSION: MILLIMETER
4. MEETS JEDEC OUTLINE MO-153. SEE JEDEC VARIATIONS TABLE
5. 'N' REFERS TO NUMBER OF LEADS
6. THE LEAD TIPS MUST LIE WITHIN A SPECIFIED ZONE. THIS TOLERANCE ZONE IS DEFINED BY TWO PARALLEL PLANES. ONE PLANE IS THE SEATING PLANE, DATUM [-C-]; THE OTHER PLANE IS AT THE SPECIFIED DISTANCE FROM [-C-] IN THE DIRECTION INDICATED

DALLAS SEMICONDUCTOR /VI/IXI/VI

PROPRIETARY INFORMATION

TITLE:
PACKAGE OUTLINE, TSSOP 4.40mm BODY

APPROVAL	DOCUMENT CONTROL NO.	REV.	
	21-0066	F	1/1

MXB7846